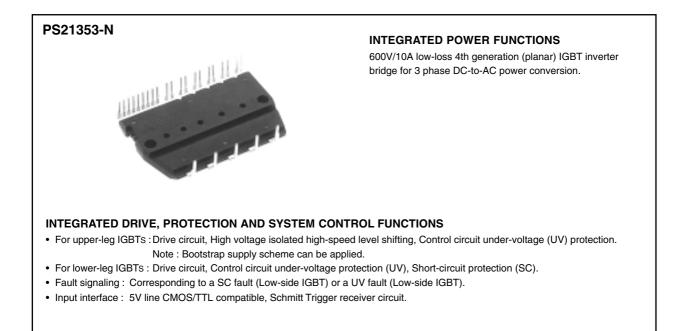
MITSUBISHI SEMICONDUCTOR <Intelligent Power Module>

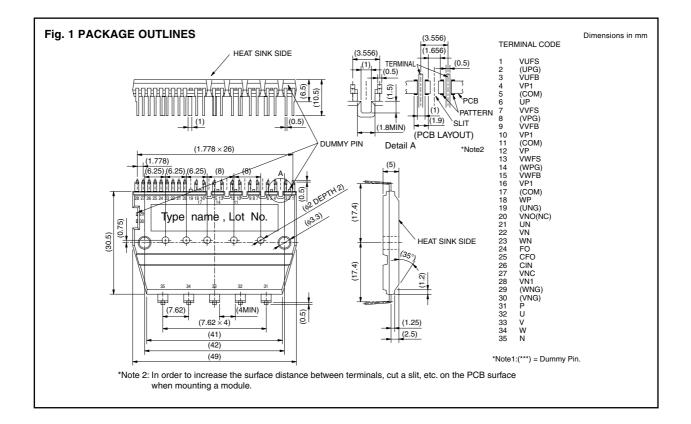
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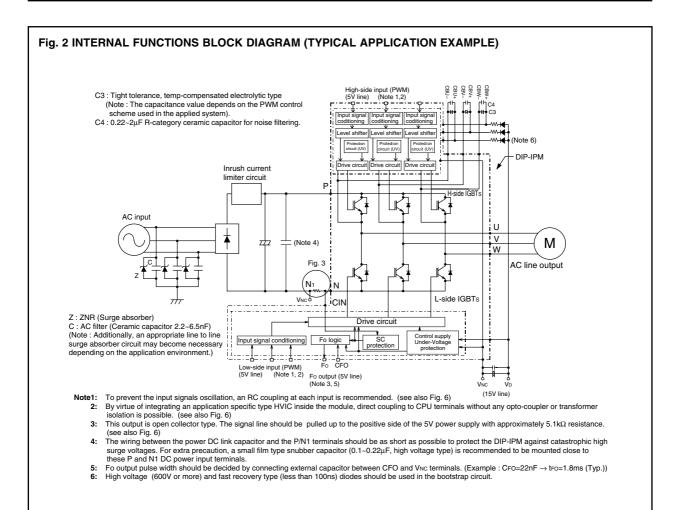
APPLICATION

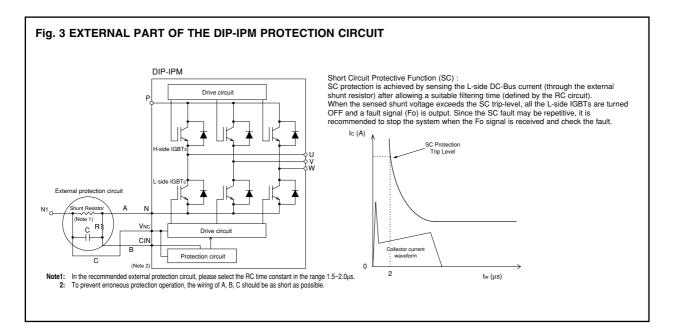
AC100V~200V inverter drive for motor control.





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MAXIMUM RATINGS (T_j = 25° C, unless otherwise noted) **INVERTER PART**

Symbol	Parameter	Condition	Ratings	Unit
Vcc	Supply voltage	Applied between P-N	450	V
VCC(surge)	Supply voltage (surge)	Applied between P-N	500	V
VCES	Collector-emitter voltage		600	V
±IC	Each IGBT collector current	Tf = 25°C	10	A
±ICP	Each IGBT collector current (peak)	Tf = 25°C, instantaneous value (pulse)	20	A
Pc	Collector dissipation	Tf = 25°C, per 1 chip	25	W
Tj	Junction temperature	(Note 1)	-20~+150	°C

Note 1 : The maximum junction temperature rating of the power chips integrated within the DIP-IPM is 150°C (@ Tf \leq 100°C). However, to ensure safe operation of the DIP-IPM, the average junction temperature should be limited to T_{j(ave)} \leq 125°C (@ Tf \leq 100°C).

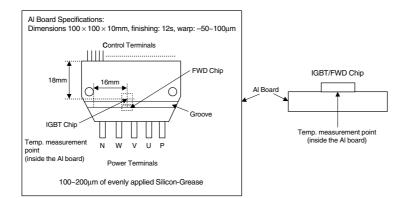
CONTROL (PROTECTION) PART

Symbol	Parameter	Condition	Ratings	Unit
VD	Control supply voltage	Applied between VP1-VNC, VN1-VNC	20	V
Vdb	Control supply voltage	Applied between VUFB-VUFS, VVFB-VVFS, VWFB-VWFS	20	V
VCIN	Input voltage	Applied between UP, VP, WP-VNC, UN, VN, WN-VNC	-0.5~VD+0.5	v
Vfo	Fault output supply voltage	Applied between FO-VNC	-0.5~VD+0.5	V
IFO	Fault output current	Sink current at Fo terminal	15	mA
Vsc	Current sensing input voltage	Applied between CIN-VNC	-0.5~VD+0.5	V

TOTAL SYSTEM

Symbol	Parameter	Condition	Ratings	Unit
VCC(PROT)	Self protection supply voltage limit (short-circuit protection capability)	$VD = VDB = 13.5 \sim 16.5V$, Inverter part T _j = 125°C, non-repetitive, less than 2 µs	400	v
Tf	Heat-fin operation temperature	(Note 2)	-20~+100	°C
Tstg	Storage temperature		-40~+125	°C
Viso	Isolation voltage	60Hz, Sinusoidal, 1 minute, connection pins to heat-sink plate	1500	Vrms

Note 2 : Tr MEASUREMENT POINT





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THERMAL RESISTANCE

Symbol Parameter	Devenenter	Condition		Limits			Linit
	Parameter			Min.	Тур.	Max.	Unit
Rth(j-f)Q	Junction-to-heat sink thermal	Inverter IGBT part (per 1/6 module)	(Note 3)	—	—	5.0	°C/W
Rth(j-f)F	resistance	Inverter FWD part (per 1/6 module)	(Note 3)	—	—	6.5	°C/W

Note 3: Grease with good thermal conductivity should be applied evenly about +100µm~+200µm on the contact surface of a DIP-IPM and a heat sink.

ELECTRICAL CHARACTERISTICS (Tj = 25° C, unless otherwise noted) **INVERTER PART**

O. mahaal	Demonstern	Condition		Condition					Unit
Symbol	Parameter			Min.	Тур.	Max.	Unit		
VCE(sat)	Collector-emitter saturation	VD = VDB = 15V	VD = VDB = 15V IC = 10A, T _i = 25°C		1.8	2.45			
voltage	VCIN = 0V	IC = 10A, Tj = 125°C	—	1.9	2.6	V			
VEC	FWD forward voltage	Tj = 25°C, -IC = 10A, VCIN = 5V		—	2.1	2.85	V		
ton		Vcc = 300V, VD = VDB = $15V$ Ic = 10A, Tj = $125^{\circ}C$ Inductive load (upper-lower arm)		0.40	0.90	1.35	μs		
trr				_	0.20	—	μs		
tc(on)	Switching times			—	0.40	0.65	μs		
toff		$V_{CIN} = 5 \leftrightarrow 0V$,	-	0.95	1.40	μs		
tc(off)				—	0.35	0.85	μs		
ICES	Collector-emitter cut-off	VCE = VCES	$T_j = 25^{\circ}C$	—	—	1	mA		
	current	VCE = VCES	Tj = 125°C	—	—	10			

CONTROL (PROTECTION) PART

O. male al	Deveryortex	Parameter Condition			Limits		Unit	
Symbol	Parameter		Condition		Тур.	Max.		
		VD = VDB =15V	Total of VP1-VNC, VN1-VNC	_	—	8.5	m 4	
ID	Circuit current	VCIN = 5V	VUFB-VUFS, VVFB-VVFS, VWFB-VWFS	—	—	1.0	mA	
U		VD = VDB =15V	Total of VP1-VNC, VN1-VNC	—	—	9.7	mA	
		VCIN = 0V	VUFB-VUFS, VVFB-VVFS, VWFB-VWFS	_	—	1.0	ШA	
VFOH		Vsc = 0V, Fo = 10kΩ 5V pull-up Vsc = 0V, IFo = 1.5mA Vsc = 1V, IFo = 15mA		4.9	-	—	V	
VFOL	Fault output voltage			—		0.9	V	
VFOsat]			0.8	1.2	1.8	V	
VSC(ref)	Short-circuit trip level	$T_j = 25^{\circ}C, V_D = 15V$ (Note 4)		0.43	0.48	0.53	V	
UVDBt			Trip level	10.0	_	12.0	V	
UVDBr	Supply circuit under-voltage	Ti ≤ 125°C	Reset level	10.5	—	12.5	V	
UVDt	protection	1]≤ 125°C	Trip level	10.3	—	12.5	V	
UVDr	1		Reset level	10.8	_	13.0	V	
tFO	Fault output pulse width	CFO = 22nF	CFO = 22nF (Note 5)		1.8	—	ms	
Vth(on)	ON threshold voltage	Applied between:	Applied between:		1.4	2.0	V	
Vth(off)	OFF threshold voltage	UP, VP, WP-VNC, U	JN, VN, WN-VNC	2.5	3.0	4.0	V	

Note 4: Short-circuit protection operates only at the low-arms. Please select the value of the external shunt resistor such that the SC trip level is less than 17A

5: Fault signal is outputted when the low-arm short-circuit or control supply under-voltage protective functions operate. The fault output pulse-width tFO depends on the capacitance value of CFO according to the following approximate equation. : CFO = (12.2 × 10⁻⁶) × tFO [F]

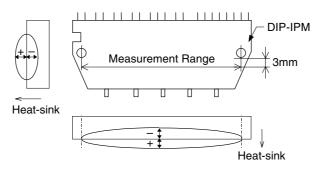


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MECHANICAL CHARACTERISTICS AND RATINGS

Devemeter	Condition				Linit		
Parameter				Min.	Тур.	Max.	Unit
Mounting torque	Mounting screw : M3		—	0.59	0.78	0.98	N∙m
Terminal pulling strength	Weight 9.8N		EIAJ-ED-4701	10	—		s
Bending strength	Weight 4.9N. 90deg bend		EIAJ-ED-4701	2	—		times
Weight			—	_	20	-	g
Heat-sink flatness	(Not	te 6)	—	-50	—	100	μm

Note 6: Measurement point of heat-sink flatness



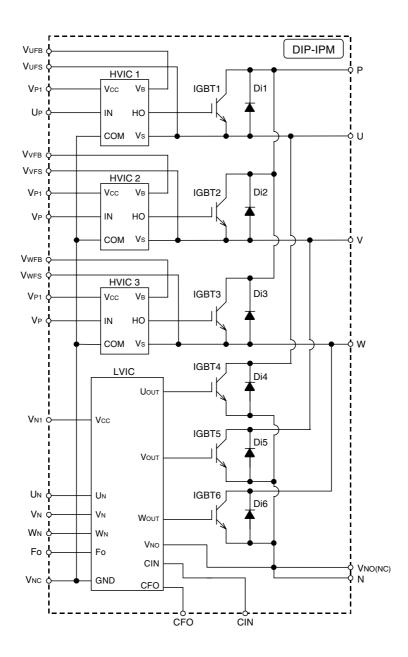
RECOMMENDED OPERATION CONDITIONS

Symbol	Deverseter	Condition		11-24			
	Parameter Condition		Min.	Тур.	Max.	Unit	
Vcc	Supply voltage	Applied between P-N		300	400	V	
Vd	Control supply voltage	Applied between VP1-VNC, VN1-VNC	13.5	15.0	16.5	V	
Vdb	Control supply voltage	Applied between VUFB-VUFS, VVFB-VVFS, VWFB-VWFS		15.0	16.5	V	
ΔV D, ΔV DB	Control supply variation			—	1	V/µs	
tdead	Arm shoot-through blocking time	For each input signal	1.5	—	—	μs	
fpwm	PWM input frequency	Tj ≤ 125°C, Tf ≤ 100°C	—	15	—	kHz	
VCIN(ON)	Input ON voltage	Applied between LID, V.D. M/D V/M/D, LNJ, V/M, M/M/D V/M/D	0~0.65			V	
VCIN(OFF)	Input OFF voltage	Applied between UP, VP, WP-VNC, UN, VN, WN-VNC		4.0~5.5			



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Fig. 4 THE DIP-IPM INTERNAL CIRCUIT



Note: The IGBTs gates and the HVICs COM terminals are connected to the dummy pins.

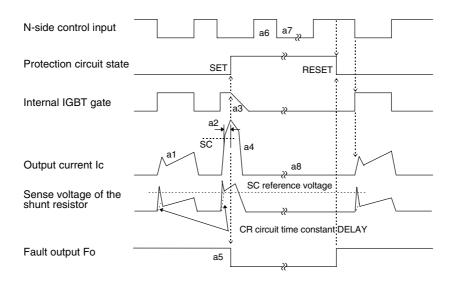


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Fig. 5 TIMING CHARTS OF THE DIP-IPM PROTECTIVE FUNCTIONS

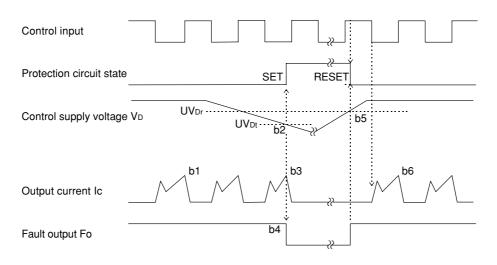
[A] Short-Circuit Protection (N-side only)

- (For the external shunt resistor and CR connection, please refer to Fig. 3.)
- a1. Normal operation : IGBT ON and carrying current.
- a2. Short-circuit current detection (SC trigger).
- a3. IGBT gate interrupt.
- a4. IGBT turns OFF.
- a5. Fo timer operation starts : The pulse width of the Fo signal is set by the external capacitor CFo.
- a6. Input "H" : IGBT OFF state. a7. Input "L" : IGBT ON state.
- a8. IGBT OFF state.



[B] Under-Voltage Protection (N-side, UVD)

- b1. Normal operation : IGBT ON and carrying current.
- b2. Under-voltage trip (UVDt).b3. IGBT OFF in spite of control input condition.
- b4. Fo timer operation starts.
- b5. Under-voltage reset (UVDr)
- b6. Normal operation : IGBT ON and carrying current.





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[C] Under-Voltage Protection (P-side, UVDB)

- c1. Control supply voltage rises : After the voltage level reachs UVDBr, the circuits start to operate when the next input is applied. c2. Normal operation : IGBT ON and carrying current. c3. Under-voltage trip (UVDBt).

- c4. IGBT OFF in spite of control input condition (there is no Fo signal output).
- c5. Under-voltage reset (UVDBr).
- c6. Normal operation : IGBT ON and carrying current.

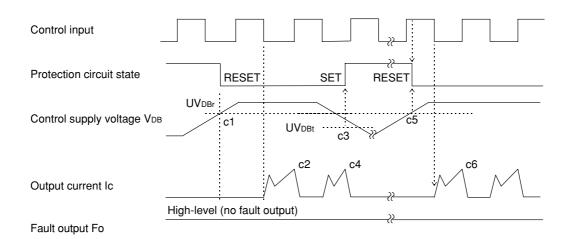
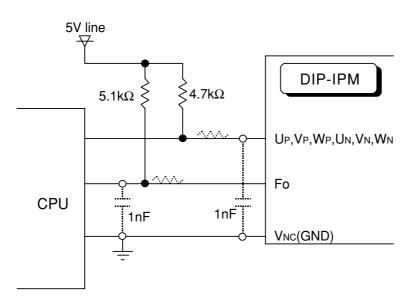


Fig. 6 RECOMMENDED CPU I/O INTERFACE CIRCUIT



Note : RC coupling at each input (parts shown dotted) may change depending on the PWM control scheme used in the application and on the wiring impedance of the application's printed circuit board.



C1: Tight tolerance temp-compensated electrolytic type; C2,C3: 0.22-2 µ F R-category ceramic capacitor for noise filtering

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C2 VUFB . _ . _ . _ . _ . _ . _ 5V line DIP-IPM VUFS Р HVIC1 VP1 ٧в Vcc UP IN нс 뉴 LI сом Vs 4.5 C2 VVFB [Ci VVFS HVIC2 VP1 Vcc ٧в ____ C3 V۶ нс ÷ сом Μ Vs C2 VWFE VWFS C1 CP HVIC3 VP1 U Vcc Ve _____ C3 WP IN HO 늞 U сом Vs W Ν LVIC I $T \Pi$ Ť Uout СЗ VN: • Vcc 5V line Vou ~~~ ş UN UN VΝ VΝ Wour If this wiring is too long, short circuit might be caused. Ì₩N WΝ Fo VNO Fo CIN 훈 4 VNC GND 77 CFO С CIN CFO ⊥́С4(С⊧о) //// R1 15V line ш P Shunt resistor C5 A N1 The long wiring of GND might generate noise on input signals and cause IGBT to be malfunctioned. If this wiring is too long, the SC level fluctuation might be large and cause SC malfunction.

Fig. 7 TYPICAL DIP-IPM APPLICATION CIRCUIT EXAMPLE

Note 1: To prevent the input signals oscillation, an RC coupling at each input is recommended, and the wiring of each input should be as short as possible (less than 2cm).

- 2: By virtue of integrating an application specific type HVIC inside the module, direct coupling to CPU terminals without any opto-coupler or transformer isolation is possible
- 3: Fo output is open collector type. This signal line should be pulled up to the positive side of the 5V power supply with approximately 5.1kΩ resistance.
- 4: Fo output pulse width should be decided by connecting an external capacitor between CFO and VNC terminals (CFO). (Example : CFO = 22 nF \rightarrow tFO = 1.8 ms (typ.))
- 5: Each input signal line should be pulled up to the positive side of the 5V power supply with approximately 4.7kΩ resistance (other RC coupling circuits at each input may be needed depending on the PWM control scheme used and on the wiring impedances of the system's printed circuit board). Approximately a 0.22-2µF by-pass capacitor should be used across each power supply connection terminals.
- 6 : To prevent errors of the protection function, the wiring of A, B, C should be as short as possible.
 7 : In the recommended protection circuit, please select the R1Cs time constant in the range of 1.5~2µs.
- 8: Each capacitor should be put as nearby the terminals of the DIP-IPM as possible.
- 9: To prevent surge destruction, the wiring between the smoothing capacitor and the P&N1 terminals should be as short as possible. Approximately a 0.1~0.22µF snubber capacitor between the P&N1 terminals is recommended.

